Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass and metal

Overall Length:

0.560 inches

Terminal Length:

1.250 inches

Overall Diameter:

0.220 inches

Function For Which Designed:

Transient suppressor

End Application:

5805-01-187-9399 switchboard, telephone automatic

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

11.1 breakdown voltage, instantaneous and 12.3 breakdown voltage, instantaneous

Current Rating Per Characteristic:

88.00 amperes source cutoff current universal

Power Rating Per Characteristic:

1.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Test Data Document:

28528-1138041 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0